

IONNYALÁB FIZIKA TEMATIKÁJÚ PUBLIKÁCIÓK (2012 ELŐTT)

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3. C. Jeynes, N.P. Barradas, E. Szilágyi:

Accurate Determination of Quantity of Material in Thin Films by Rutherford Backscattering Spectrometry

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4. J. Budai, I. Hanyecz, E. Szilágyi, Zs. Tóth:

Ellipsometric study of SixC films: Analysis of Tauc–Lorentz and Gaussian oscillator models

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